



# **MUR30120PT**

### **FEATURES**

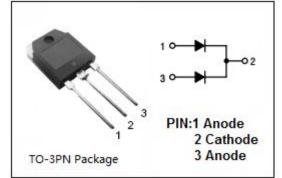
- Guarding for over voltage protection
- · Dual rectifier construction, positive center tap
- · Metal of silicon rectifier, majority carrier conduction
- Low forward voltage, high efficiency
- 100% tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

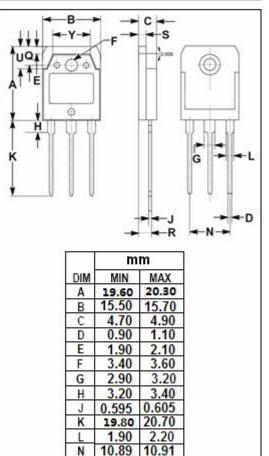
### **APPLICATIONS**

- Switching power supply
- · Rectifier in switch mode supplies

## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL   | PARAMETER  | VALUE   | UNIT |
|--|--|---------|------|
| V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                         | 1200    | V    |
| I <sub>F(AV)</sub>                                     | Average Rectified Forward Current  | 30      | A    |
| IFSM   | Nonrepetitive Peak Surge Current<br>(Surge applied at rated load conditions half-<br>wave, single phase, 60Hz) | 150     | A    |
| PD   | Maximum power dissipation  | 78      | W    |
| TJ   | Junction Temperature   | -40~150 | °C   |
| T <sub>stg</sub>                                       | Storage Temperature Range  | -40~150 | °C   |





10.9

5.10

3 45

2.100

6.20

9.90 10.10

1

N

Q

R

s

U Y

4.90

3.35

5.90

1.995



# INCHANGE SEMICONDUCTOR

# **Fast Recovery Rectifier**

# MUR30120PT

### THERMAL CHARACTERISTICS

| SYMBOL              | PARAMETER                            | МАХ | UNIT |
|---------------------|--------------------------------------|-----|------|
| R <sub>th j-c</sub> | Thermal Resistance, Junction to Case |     | °C/W |

#### **ELECTRICAL CHARACTERISTICS(Ta=25℃)** (Pulse Test: Pulse Width=300 µ s,Duty Cycle≤2%)

| SYMBOL         | PARAMETER                             | CONDITIONS  | MAX                | UNIT |
|----------------|---------------------------------------|---|--------------------|------|
| VF             | Maximum Instantaneous Forward Voltage | I <sub>F</sub> = 15A ;Tj=150°C<br>I <sub>F</sub> = 15A ;Tj=25°C   | 2.6<br>2.2         | V    |
| I <sub>R</sub> | Maximum Instantaneous Reverse Current | V <sub>R</sub> = V <sub>RWM;</sub> Tj=25°C<br>V <sub>R</sub> = 0.8V <sub>RWM;</sub> Tj=25°C<br>V <sub>R</sub> = 0.8V <sub>RWM;</sub> Tj=125°C | 250<br>150<br>4000 | μA   |
| trr            | Maximum Reverse Recovery Time         | IF =1A;   | 70                 | ns   |

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